NSN 5961-01-190-4782

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-190-4782 **Inclosure Material:** Metal **Overall Length:** 0.210 inches **Terminal Length:** 0.500 inches **Overall Diameter:** 0.205 inches **End Application:** 4920-01-111-2981 **Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-92 **Mounting Method: Terminal Terminal Circle Diameter:** 0.100 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 200.0 repetitive peak off-state voltage **Current Rating Per Characteristic:** 0.80 amperes forward current, total rms horsepower metric and 8.00 amperes peak forward surge current preset **Power Rating Per Characteristic:** 0.01 watts small-signal input power, common-collector universal **Maximum Operating Tempurature Per Measurement Point:** 110.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pn **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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